

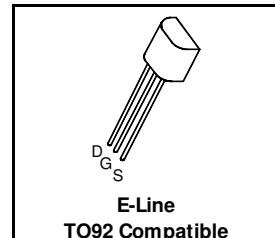
# P-CHANNEL ENHANCEMENT MODE VERTICAL DMOS FET

ISSUE 2 – MARCH 94

## FEATURES

- \* 60 Volt  $V_{DS}$
- \*  $R_{DS(on)}=5\Omega$

**ZVP2106A**



## ABSOLUTE MAXIMUM RATINGS.

PARAMETER	SYMBOL	VALUE	UNIT
Drain-Source Voltage	$V_{DS}$	-60	V
Continuous Drain Current at $T_{amb}=25^\circ C$	$I_D$	-280	mA
Pulsed Drain Current	$I_{DM}$	-4	A
Gate Source Voltage	$V_{GS}$	$\pm 20$	V
Power Dissipation at $T_{amb}=25^\circ C$	$P_{tot}$	700	mW
Operating and Storage Temperature Range	$T_j \cdot T_{stg}$	-55 to +150	°C

## ELECTRICAL CHARACTERISTICS (at $T_{amb} = 25^\circ C$ unless otherwise stated).

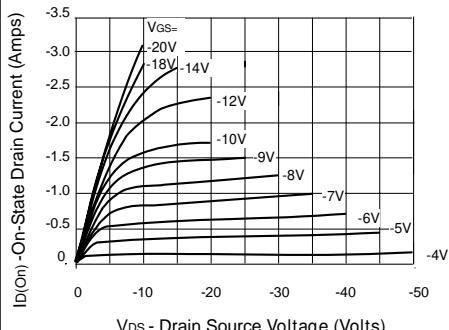
PARAMETER	SYMBOL	MIN.	MAX.	UNIT	CONDITIONS.
Drain-Source Breakdown Voltage	$BV_{DSS}$	-60		V	$I_D=-1\text{ mA}, V_{GS}=0\text{V}$
Gate-Source Threshold Voltage	$V_{GS(th)}$	-1.5	-3.5	V	$ID=-1\text{ mA}, V_{DS}=V_{GS}$
Gate-Body Leakage	$I_{GSS}$		20	nA	$V_{GS}=\pm 20\text{V}, V_{DS}=0\text{V}$
Zero Gate Voltage Drain Current	$I_{DSS}$		-0.5 -100	$\mu\text{A}$ $\mu\text{A}$	$V_{DS}=-60\text{ V}, V_{GS}=0$ $V_{DS}=-48\text{ V}, V_{GS}=0\text{V}, T=125^\circ\text{C}(2)$
On-State Drain Current(1)	$I_{D(on)}$	-1		A	$V_{DS}=-18\text{ V}, V_{GS}=-10\text{V}$
Static Drain-Source On-State Resistance (1)	$R_{DS(on)}$		5	$\Omega$	$V_{GS}=-10\text{V}, I_D=-500\text{mA}$
Forward Transconductance (1)(2)	$g_{fs}$	150		$\text{mS}$	$V_{DS}=-18\text{V}, I_D=-500\text{mA}$
Input Capacitance (2)	$C_{iss}$		100	pF	$V_{DS}=-18\text{V}, V_{GS}=0\text{V}, f=1\text{MHz}$
Common Source Output Capacitance (2)	$C_{oss}$		60	pF	
Reverse Transfer Capacitance (2)	$C_{rss}$		20	pF	
Turn-On Delay Time (2)(3)	$t_{d(on)}$		7	ns	$V_{DD} \approx -18\text{V}, I_D=-500\text{mA}$
Rise Time (2)(3)	$t_r$		15	ns	
Turn-Off Delay Time (2)(3)	$t_{d(off)}$		12	ns	
Fall Time (2)(3)	$t_f$		15	ns	

(1) Measured under pulsed conditions. Width=300μs. Duty cycle ≤2%

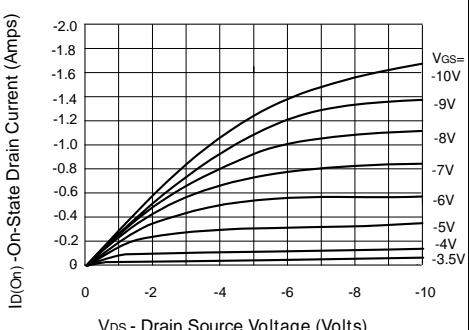
(2) Sample test.

# ZVP2106A

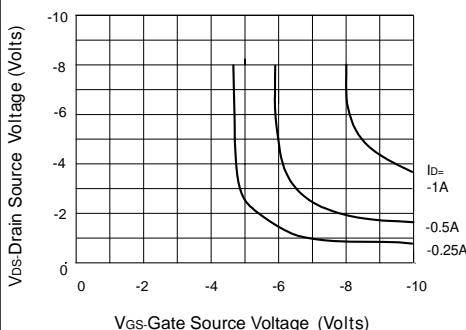
## TYPICAL CHARACTERISTICS



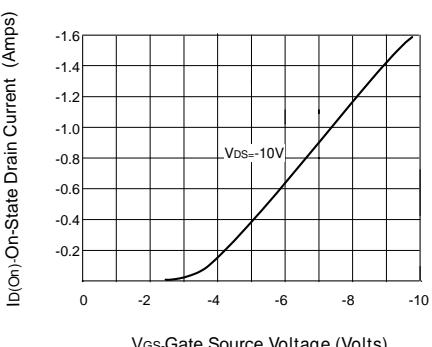
**Output Characteristics**



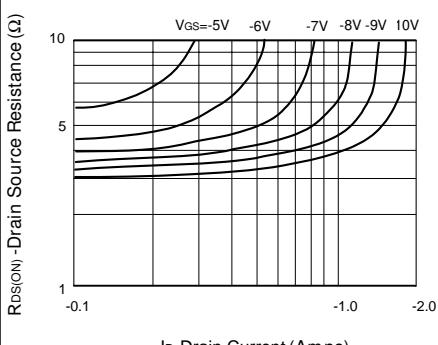
**Saturation Characteristics**



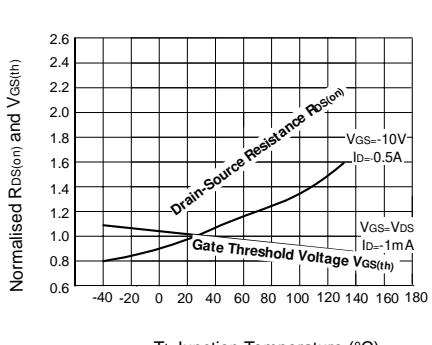
**Voltage Saturation Characteristics**



**Transfer Characteristics**



**On-resistance v drain current**



**Normalised  $R_{DS(on)}$  and  $V_{GS(th)}$  vs Temperature**

**TYPICAL CHARACTERISTICS**